NSN 5961-01-086-0447

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-086-0447 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **End Application:** Helicopter, iroquois hh/uh-1; cobra helicopter; cobra attack helicopter; helicopter, advance attack **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.677 inches and 0.687 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 2.00 milliamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Hardware included; weapon system essential; junction pattern arrangement: pn **Thread Series Designator: Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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